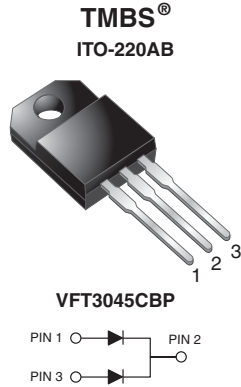


Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

 Ultra Low $V_F = 0.30\text{ V}$ at $I_F = 5.0\text{ A}$


FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- T_J 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 15 A
V_{RRM}	45 V
I_{FSM}	200 A
V_F at $I_F = 15\text{ A}$	0.39 V
T_{OP} max. (AC mode)	150 °C
T_J max. (DC forward current)	200 °C
Package	ITO-220AB
Diode variation	Dual common cathode

MECHANICAL DATA

Case: ITO-220AB

 Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VFT3045CBP	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$ ⁽¹⁾	per device	30
		per diode	15
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	200	A
Isolation voltage from terminal to heatsink, $t = 1\text{ min}$	V_{AC}	1500	V
Operating junction and storage temperature range (AC mode)	T_{OP}, T_{STG}	-40 to +150	°C
Junction temperature in DC forward current without reverse bias, $t \leq 1\text{ h}$	T_J ⁽²⁾	≤ 200	°C

Notes

⁽¹⁾ With heatsink

⁽²⁾ Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.42	-	V
	I _F = 7.5 A			0.44	-	
	I _F = 15 A			0.49	0.57	
	I _F = 5 A	T _A = 125 °C		0.30	-	
	I _F = 7.5 A			0.33	-	
	I _F = 15 A			0.39	0.48	
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	2000	μA
		T _A = 125 °C		17	50	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VFT3045CBP	UNIT
Typical thermal resistance	per diode	R _{θJC}	6.0	°C/W
	per device		4.0	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VFT3045CBP-M3/4W	1.76	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

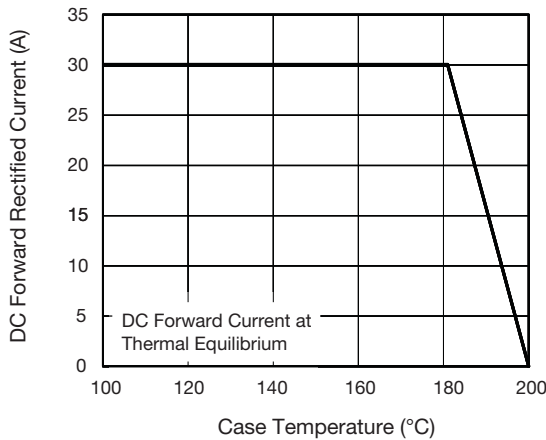


Fig. 1 - Maximum Forward Current Derating Curve

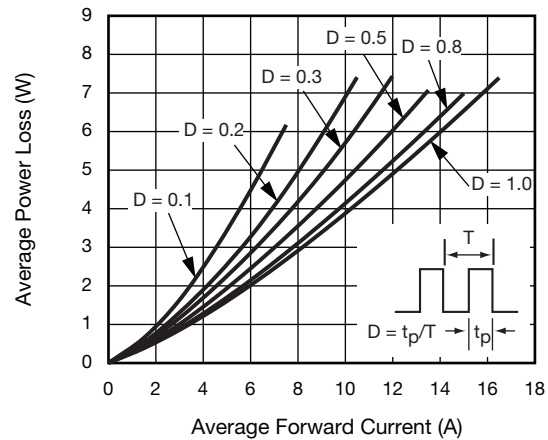


Fig. 2 - Forward Power Loss Characteristics Per Diode

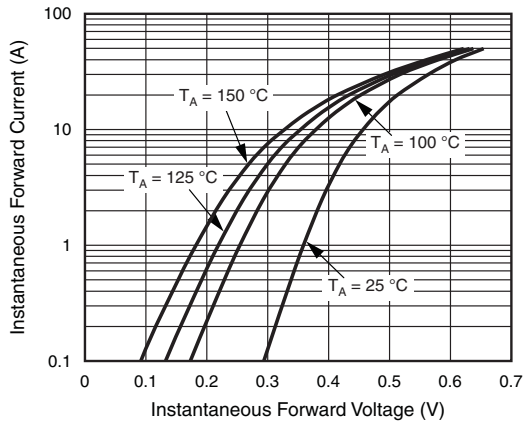


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

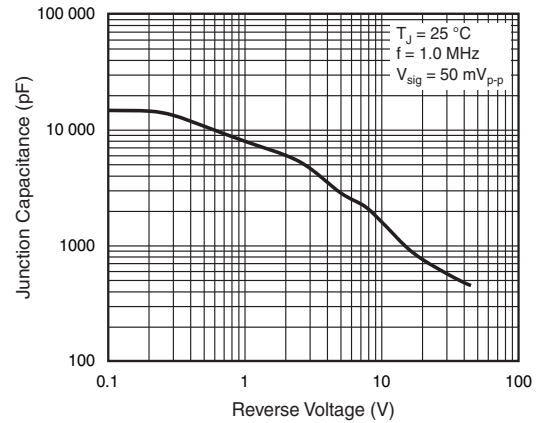


Fig. 5 - Typical Junction Capacitance Per Diode

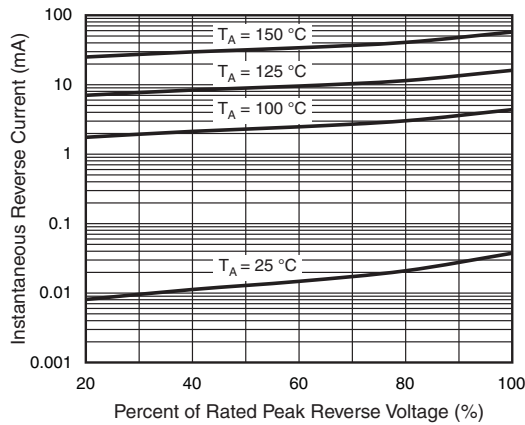


Fig. 4 - Typical Reverse Characteristics Per Diode

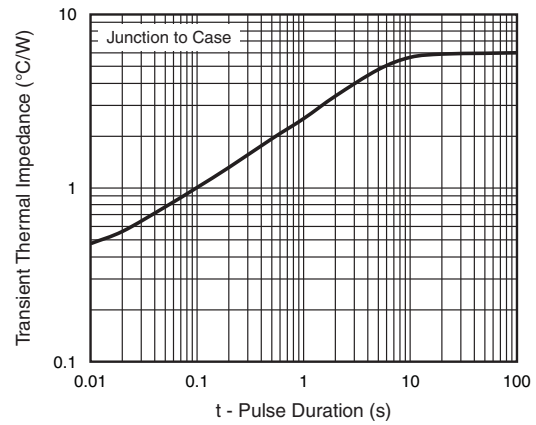
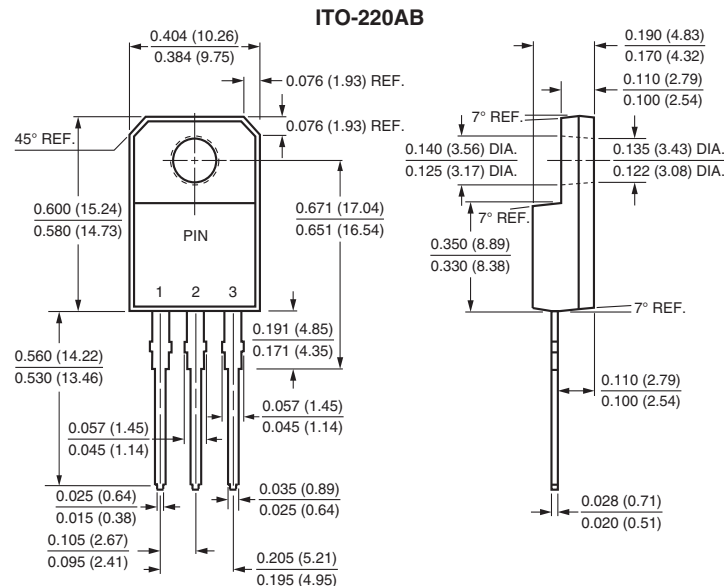


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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